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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Alexei A. Erchak et al.
Serial No. : 10/723,987
Filed : November 26, 2003
Title : LIGHT EMITTING DIODES

Art Unit : Unknown
Examiner : Unknown

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Copies of the non-patent references listed on the attached form PTO-1449 are enclosed. Applicants also bring to the Examiner's attention the below listed 14 pending U.S. utility patent applications that are owned by the Assignee of the above-noted patent application.

Document Number	Patentee	Filing Date
10/724,004	Alexei A. Erchak	11/26/03
10/724,033	Alexei A. Erchak	11/26/03
10/724,006	Alexei A. Erchak	11/26/03
10/724,029	Alexei A. Erchak	11/26/03
10/724,015	Alexei A. Erchak	11/26/03
10/724,005	Alexei A. Erchak	11/26/03
10/735,498	Alexei A. Erchak	12/12/03
10/794,244	Alexei A. Erchak	3/5/04
10/794,452	Alexei A. Erchak	3/5/04
10/872,335	Alexei A. Erchak et al.	6/18/04
10/896,606	Alexei A. Erchak et al.	7/22/04
10/871,877	Alexei A. Erchak et al.	6/18/04
10/872,336	Alexei A. Erchak et al.	6/18/04
10/896,435	Alexei A. Erchak et al.	7/22/04

This statement is being filed after a first Office action on the merits, but before receipt of a final Office action or a Notice of Allowance. A check for \$180 in payment of the late

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September 24, 2004

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Applicant : Alexei A. Erchak et al.
Serial No. : 10/723,987
Filed : November 26, 2003
Page : 2 of 2

Attorney's Docket No.: 16459-006001 / LD-4

submission fee of §1.17(p) is enclosed. Please apply any other charges or credits to Deposit
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Respectfully submitted,

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9/27/04



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Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 16459-006001	Application No. 10/723,987
	Applicant Alexei A. Erchak et al.		
	Filing Date November 26, 2003	Group Art Unit	

U.S. Patent Documents

Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,359,345	10/25/94	Hunter et al.			
	AB	5,631,190	05/20/97	Negley et al.			
	AC	5,724,062	03/03/98	Hunter et al.			
	AD	5,799,924	07/14/98	Krames et al.			
	AE	5,955,749	09/21/99	Joannopoulos et al.			
	AF	6,071,795	06/06/00	Cheung et al.			
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	AO	5,426,657	06/20/1995	Vakhsoori			05/27/94

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AP	WO 98/14986	04/09/98	PCT				

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
	AQ	W.S. Wong et al. "Damage-free separation of GaN thin films from sapphire substrates", Appl. Phys. Lett. 72 (5), February 2, 1998, pages 599-601
	AR	M.K. Kelly et al. "Optical process for liftoff of Group III-nitride films", Physica Status Solidi; Rapid Research Note, November 28, 1996, 2 pages.
	AS	A. A. Erchak et al. "Enhanced coupling to vertical radiation using a two-dimensional photonic crystal in a semiconductor light-emitting diode", Appl. Phys. Lett. (78 (5), January 29, 2001, pages 563-565

Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 16459-006001	Application No. 10/723,987
Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Alexei A. Erchak et al.	
		Filing Date November 26, 2003	Group Art Unit

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
	AT	P.L. Gourley et al. "Optical properties of two-dimensional photonic lattices fabricated as honeycomb nanostructures in compound semiconductors", Appl. Phys. Lett. 64(6), February 7, 1994, pages 687-689
	AU	P.L. Gourley et al. "Optical Bloch waves in a semiconductor photonic lattice", Appl. Phys. Lett. 60 (22), June 1, 1992, pages 2714-2716
	AV	J.R. Wendt et al. "Nanofabrication of photonic lattice structures in GaAs/AlGaAs", J.Vac. Sci. Technol. B 11(6), November/December 1993, pages 2637-2640
	AW	M. Krames et al. "Introduction to the Issue on High-Efficiency Light-Emitting Diodes", IEEE Journal on selected topic in quantum electronics, Vol. 8, No. 2 March/April 2002, pages 185-188
	AX	K. Streubel et al. "High Brightness AlGaInP Light-Emitting Diodes", IEEE Journal on selected topic in quantum electronics, Vol. 8, No. 2, March/April 2002, pages 321-332
	AY	M. Okai et al. "Novel method to fabricate corrugation for a $\lambda/4$ -shifted distributed feedback laser using a grating photomask", Appl. Phys. Lett. 55(5), July 31, 1989, pages 415-417
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	ADD	Y.-J. Lee et al. "A high-extraction-efficiency nanopatterned organic light-emitting diode", Appl. Phys. Lett. 82(21), May 26, 2003, pages 3779-3781
	AEE	I. Schnitzer et al. "30% external quantum efficiency from surface textured, thin-film light-emitting diodes", Appl. Phys. Lett. 63 (18), October 18, 1993, pages 2174-2176
	AFF	M. Boroditsky et al. "Light extraction from optically pumped light-emitting diode by thin-slab photonic crystals", Appl. Phys. Lett. 75 (8), August 23, 1999, pages 1036-1038
	AGG	L. Chen et al. "Fabrication of 50-100 nm Patterned InGaN Blue Light Emitting Heterostructures", Phys. Stat. Sol. (a), 188 (1), 2001, pages 135-138.
	AHH	I. Bulu et al. "Highly directive radiation from sources embedded inside photonic crystals", Appl. Phys. Lett. 83 (16), October 20, 2003, pages 3263-3265
	AII	T. N. Oder et al. "III-nitride photonic crystals", Appl. Phys. Lett. 83 (6), August 11, 2003, pages 1231-1233
	AJJ	M.K. Kelly et al. "Optical patterning of GaN films", Appl. Phys. Lett 68 (12), September 16, 1996, pages 1749-1751

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